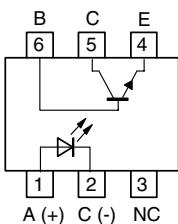
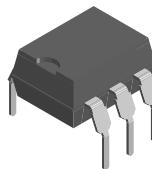


Optocoupler, Phototransistor Output



17186



FEATURES

- Special construction: therefore, extra low coupling capacity of typical 0.2 pF, high common mode rejection
- Low temperature coefficient of CTR
- Rated isolation voltage (RMS includes DC) $V_{IOWM} = 600 \text{ V}_{\text{RMS}}$ (848 V peak)
- Rated recurring peak voltage (repetitive) $V_{IORM} = 600 \text{ V}_{\text{RMS}}$
- Thickness through insulation $\geq 0.75 \text{ mm}$
- Creepage current resistance according to VDE 0303/ IEC 60112 comparative tracking index: **CTI ≥ 275**
- Rated impulse voltage (transient overvoltage) $V_{IOTM} = 6 \text{ kV}$ peak
- Isolation test voltage (partial discharge test voltage) $V_{pd} = 1.6 \text{ kV}$
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



DESCRIPTION

The 4N25V/4N25GV/4N35V/4N35GV series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 6-lead plastic dual inline package.

The elements are mounted on one leadframe using a **coplanar technique**, providing a fixed distance between input and output for highest safety requirements.

VDE STANDARDS

These couplers perform safety functions according to the following equipment standards:

DIN EN 60747-5-5

Optocoupler for electrical safety requirements

IEC 60950

Office machines (applied for reinforced isolation for mains voltage $\leq 400 \text{ V}_{\text{RMS}}$)

VDE 0804

Telecommunication apparatus and data processing

IEC 60065

Safety for mains-operated electronic and related household apparatus

APPLICATIONS

- Switch-mode power supplies
 - Line receiver
 - Computer peripheral interface
 - Microprocessor system interface
 - Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
 - for appl. class I - IV at mains voltage $\leq 300 \text{ V}$
 - for appl. class I - III at mains voltage $\leq 600 \text{ V}$
- according to DIN EN 60747-5-5

AGENCY APPROVALS

- UL1577, file no. E76222 system code A, double protection
- BSI: BS EN 41003, BS EN 60065 (BS 415), certificate number 7081 and 7402
- DIN EN 60747-5-5
- VDE related features:
FIMKO (SETI): EN 60950, certificate no. 12399

ORDER INFORMATION

PART	REMARKS
4N25V	CTR > 20 % wide lead spacing, DIP-6
4N35GV	CTR > 100 % wide lead spacing, DIP-6
4N25V	CTR > 20 %, DIP-6
4N35V	CTR > 100 %, DIP-6

Note

G = leadform 10.16 mm; G is not marked on the body.

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	5	V
Forward current		I _F	60	mA
Forward surge current	t _P ≤ 10 μs	I _{FSM}	3	A
Power dissipation		P _{diss}	100	mW
Junction temperature		T _j	125	°C
OUTPUT				
Collector emitter voltage		V _{CEO}	32	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		I _C	50	mA
Collector peak current	t _P /T = 0.5, t _P ≤ 10 ms	I _{CM}	100	mA
Power dissipation		P _{diss}	150	mW
Junction temperature		T _j	125	°C
COUPLER				
Isolation test voltage (RMS)		V _{ISO}	5300	V _{RMS}
Total power dissipation		P _{tot}	250	mW
Ambient temperature range		T _{amb}	- 55 to + 100	°C
Storage temperature range		T _{stg}	- 55 to + 125	°C
Soldering temperature	2 mm from case, t ≤ 10 s	T _{sld}	260	°C

Note

T_{amb} = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I _F = 50 mA	V _F		1.2	1.4	V
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j		50		pF
OUTPUT						
Collector emitter voltage	I _C = 1 mA	V _{CEO}	32			V
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V
Collector emitter leakage current	V _{CE} = 10 V, I _F = 0, T _{amb} = 100 °C	I _{CEO}			50	nA
	V _{CE} = 30 V, I _F = 0, T _{amb} = 100 °C	I _{CEO}			500	nA
COUPLER						
Collector emitter saturation voltage	I _F = 50 mA, I _C = 2 mA	V _{CEsat}			0.3	V
Cut-off frequency	V _{CE} = 5 V, I _F = 10 mA, R _L = 100 Ω	f _c		110		kHz
Coupling capacitance	f = 1 MHz	C _k		1		pF

Note

T_{amb} = 25 °C, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$V_{CE} = 10 \text{ V}, I_F = 10 \text{ mA}$	4N25V	CTR	20	100		\%
		4N25GV	CTR				
		4N35V	CTR	100	150		\%
		4N35GV	CTR				
	$V_{CE} = 10 \text{ V}, I_F = 10 \text{ mA}, T_{amb} = 100^\circ\text{C}$	4N35V	CTR	40			\%
		4N35GV	CTR				

MAXIMUM SAFETY RATINGS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward current		I_F			130	mA
OUTPUT						
Power dissipation		P_{diss}			265	mW
COUPLER						
Rated impulse voltage		V_{IOTM}			6	kV
Safety temperature		T_{si}			150	°C

Note

According to DIN EN 60747-5-5 (see figure 1). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	$100\%, t_{test} = 1 \text{ s}$	V_{pd}	1600			V
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)	V_{IOTM}	6000			V
Insulation resistance	$V_{IO} = 500 \text{ V}$	R_{IO}	10^{12}			Ω
	$V_{IO} = 500 \text{ V}, T_{amb} = 100^\circ\text{C}$	R_{IO}	10^{11}			Ω
	$V_{IO} = 500 \text{ V}, T_{amb} = 150^\circ\text{C}$ (construction test only)	R_{IO}	10^9			Ω

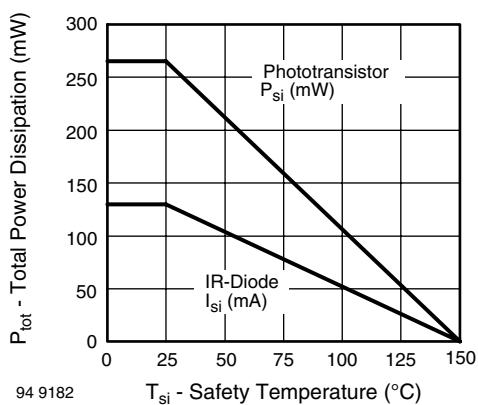


Fig. 1 - Derating Diagram

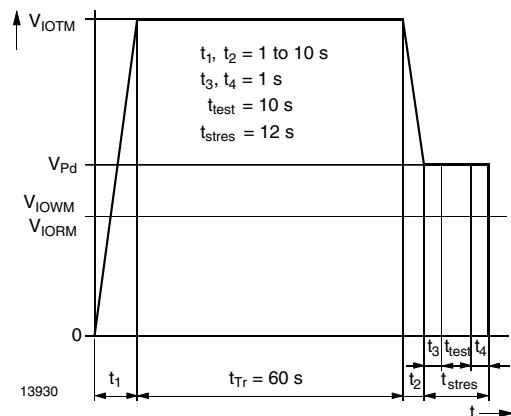
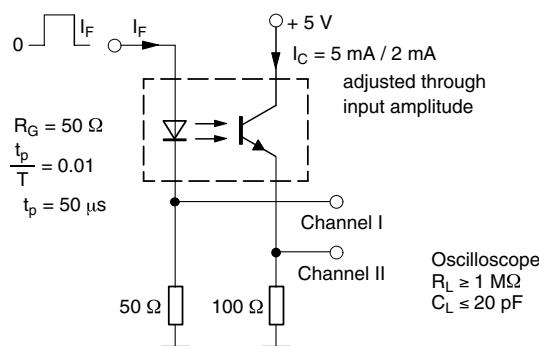


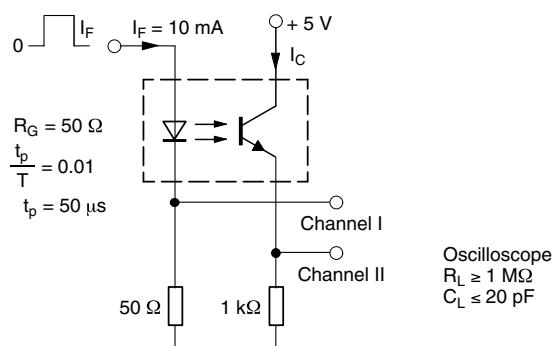
Fig. 2 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5; IEC 60747

SWITCHING CHARACTERISTICS

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time (see figure 3)	$V_S = 5 \text{ V}$, $I_C = 5 \text{ mA}$, $R_L = 100 \Omega$,	4N25V 4N25GV	t_d		4		μs
	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$,	4N35V 4N35GV	t_d		2.5		μs
Rise time (see figure 3)	$V_S = 5 \text{ V}$, $I_C = 5 \text{ mA}$, $R_L = 100 \Omega$,	4N25V 4N25GV	t_r		7		μs
	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$,	4N35V 4N35GV	t_r		3		μs
Fall time (see figure 3)	$V_S = 5 \text{ V}$, $I_C = 5 \text{ mA}$, $R_L = 100 \Omega$,	4N25V 4N25GV	t_f		6.7		μs
	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$,	4N35V 4N35GV	t_f		4.2		μs
Storage time (see figure 3)	$V_S = 5 \text{ V}$, $I_C = 5 \text{ mA}$, $R_L = 100 \Omega$,	4N25V 4N25GV	t_s		0.3		μs
	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$,	4N35V 4N35GV	t_s		0.3		μs
Turn-on time (see figure 3)	$V_S = 5 \text{ V}$, $I_C = 5 \text{ mA}$, $R_L = 100 \Omega$,	4N25V 4N25GV	t_{on}		11		μs
	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$,	4N35V 4N35GV	t_{on}			10.0	μs
Turn-off time (see figure 3)	$V_S = 5 \text{ V}$, $I_C = 5 \text{ mA}$, $R_L = 100 \Omega$,	4N25V 4N25GV	t_{off}		7		μs
	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$,	4N35V 4N35GV	t_{off}			10.0	μs
Turn-on time (see figure 4)	$V_S = 5 \text{ V}$, $I_F = 10 \text{ mA}$, $R_L = 1 \text{ k}\Omega$,	4N25V 4N25GV	t_{on}		25		μs
		4N35V 4N35GV	t_{on}		9		μs
Turn-off time (see figure 4)	$V_S = 5 \text{ V}$, $I_F = 10 \text{ mA}$, $R_L = 1 \text{ k}\Omega$,	4N25V 4N25GV	t_{off}		42.5		μs
		4N35V 4N35GV	t_{off}		25		μs



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Fig. 3 - Test circuit, Non-Saturated Operation

Fig. 4 - Test Circuit, Saturated Operation

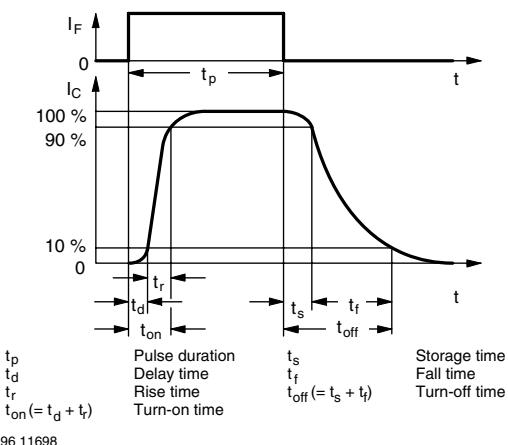


Fig. 5 - Switching Times

TYPICAL CHARACTERISTICS

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

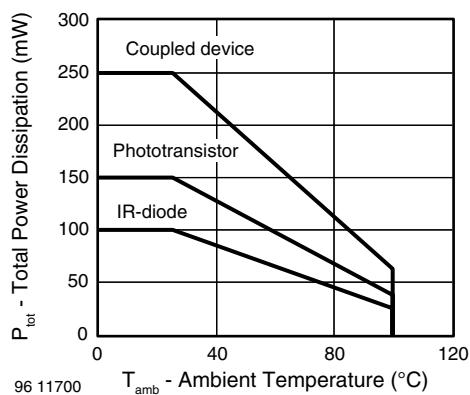


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

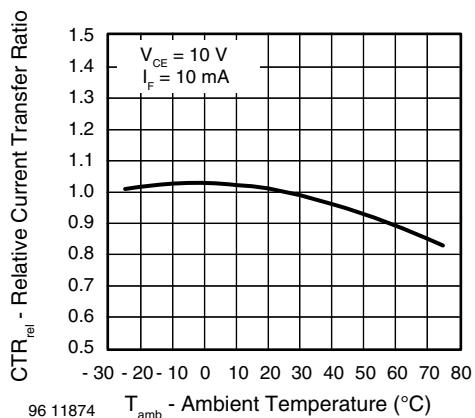


Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

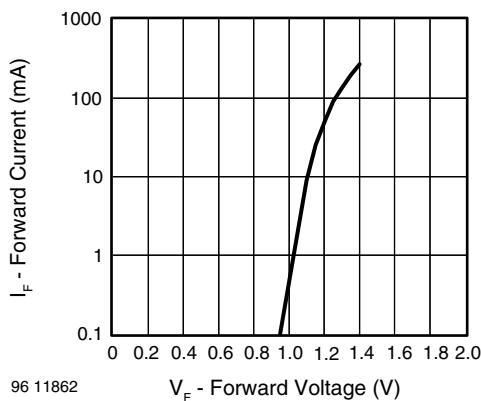


Fig. 7 - Forward Current vs. Forward Voltage

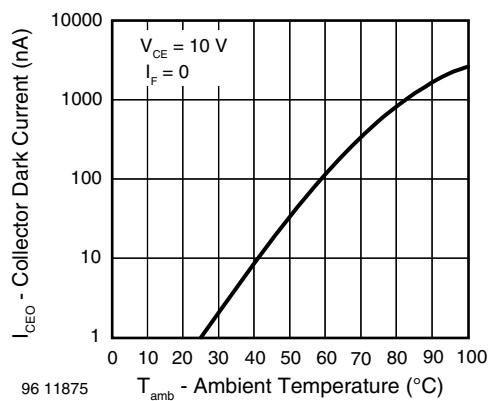


Fig. 9 - Collector Dark Current vs. Ambient Temperature

4N25V/4N25GV/4N35V/4N35GV

Vishay Semiconductors Optocoupler, Phototransistor Output

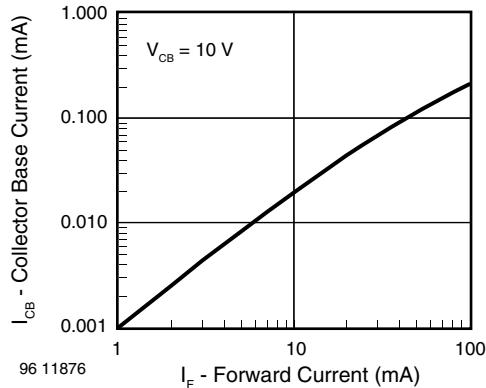


Fig. 10 - Collector Base Current vs. Forward Current

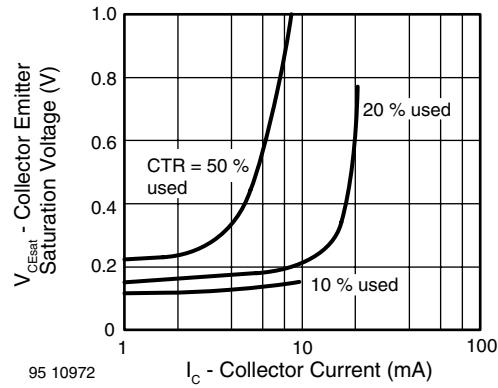


Fig. 13 - Collector Emitter Saturation Voltage vs. Collector Current

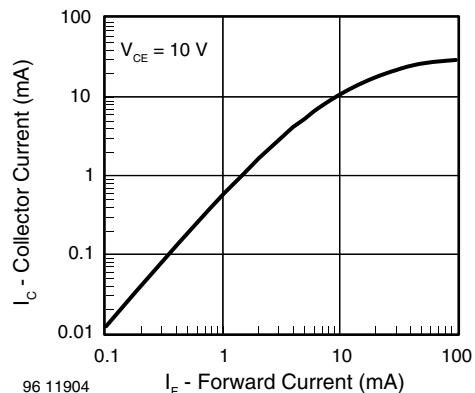


Fig. 11 - Collector Current vs. Forward Current

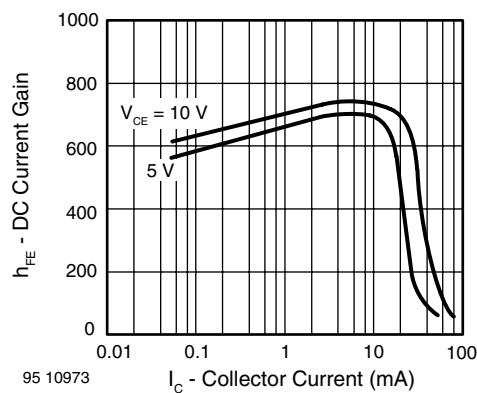


Fig. 14 - DC Current Gain vs. Collector Current

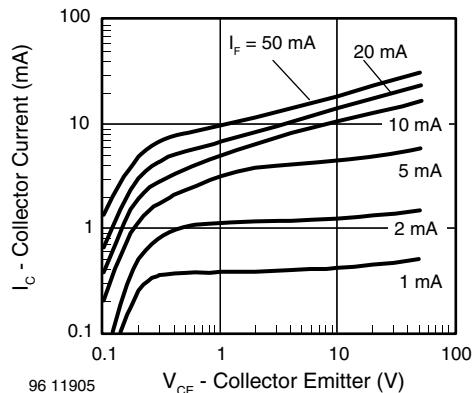


Fig. 12 - Collector Current vs. Collector Emitter Voltage

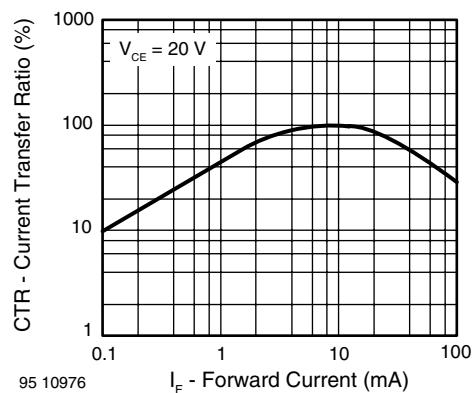


Fig. 15 - Current Transfer Ratio vs. Forward Current

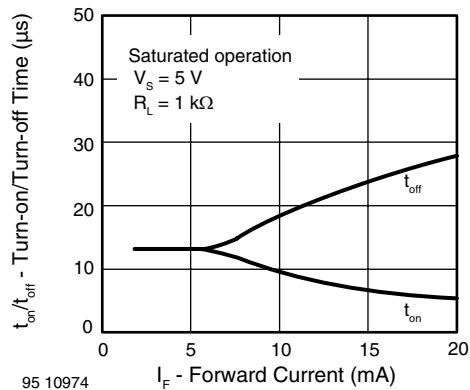


Fig. 16 - Turn-on/-off Time vs. Forward Current

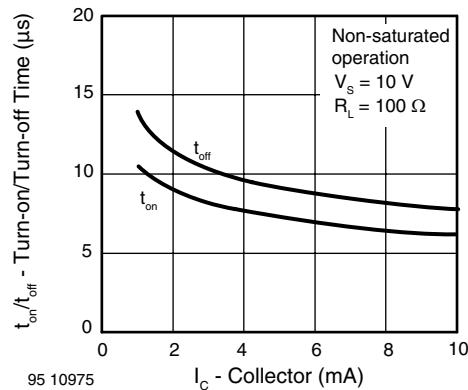
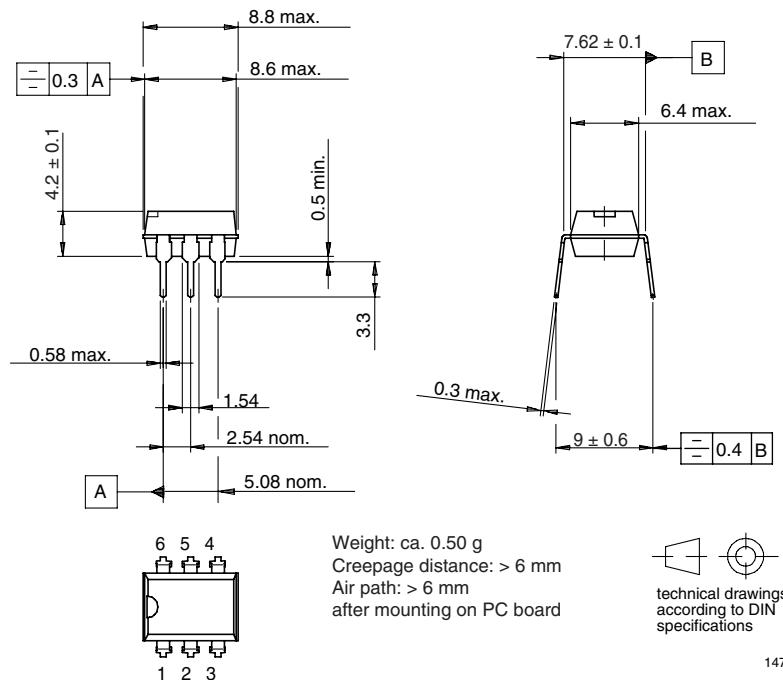
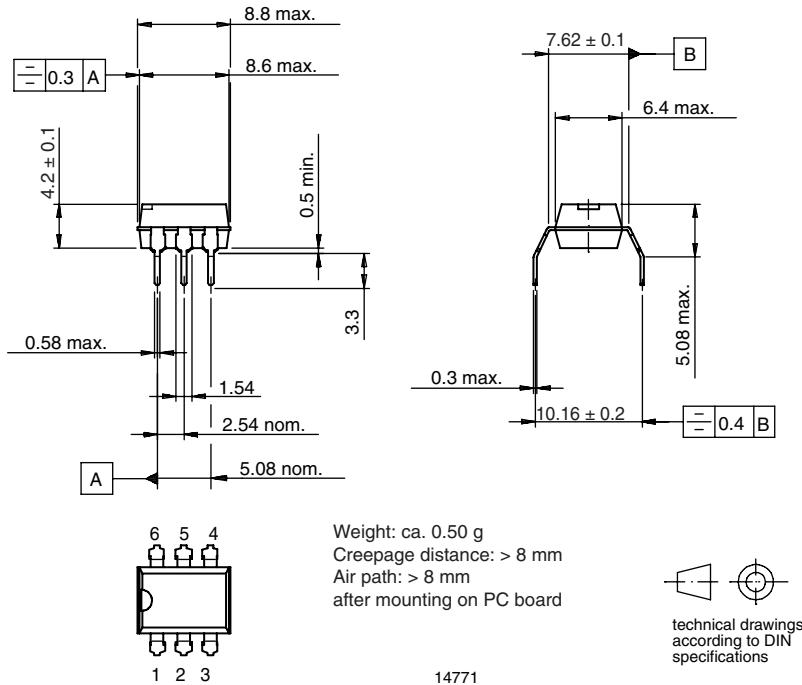


Fig. 17 - Turn-on/-off Time vs. Collector Current

PACKAGE DIMENSIONS in millimeters



PACKAGE DIMENSIONS in millimeters

**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

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